

BF178
SILICON
NPN TRANSISTOR



TO-39 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR BF178 is a silicon NPN transistor, mounted in a hermetically sealed package, designed for general purpose amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Emitter Voltage	V_{CER}	185	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I_C	50	mA
Continuous Base Current	I_B	10	mA
Power Dissipation	P_D	1.7	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

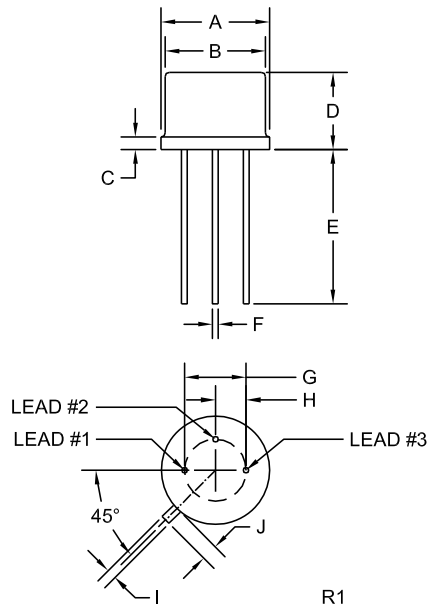
ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CES}	$V_{CE}=185\text{V}$			1.0	mA
BV_{CBO}	$I_C=1.0\text{mA}$	185			V
BV_{CER}	$I_C=1.0\text{mA}, R_{BE}=1.0\text{k}\Omega$	185			V
BV_{CEO}	$I_C=10\text{mA}$	115			V
BV_{EBO}	$I_E=100\mu\text{A}$	5.0			V
$V_{BE(ON)}$	$V_{CE}=20\text{V}, I_C=30\text{mA}$			1.2	V
h_{FE}	$V_{CE}=20\text{V}, I_C=30\text{mA}$	20			
f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}$		120		MHz

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TO-39 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

R0 (2-May 2017)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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